

**tert-Butoxytriphenylsilane**

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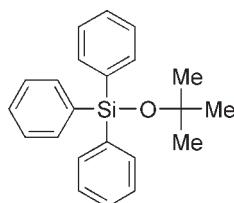
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Key indicators: single-crystal X-ray study;  $T = 173\text{ K}$ ; mean  $\sigma(\text{C}-\text{C}) = 0.003\text{ \AA}$ ;  $R$  factor = 0.042;  $wR$  factor = 0.100; data-to-parameter ratio = 19.1.

The title compound,  $\text{C}_{22}\text{H}_{24}\text{OSi}$  or  $\text{Ph}_3\text{SiO}'\text{Bu}$ , shows a distorted tetrahedral coordination sphere around the Si atom. The  $\text{C}-\text{O}-\text{Si}$  angle is  $135.97(12)^\circ$  and the  $\text{O}-\text{Si}$  distance is  $1.6244(13)\text{ \AA}$ . The molecules are held together by weak interactions only. An  $\text{H}\cdots\text{H}$  distance of  $2.2924(7)\text{ \AA}$  is found between aryl H atoms and is the shortest intermolecular distance in the structure. With regard to the broad applicability of  $\text{R}_3\text{SiO}$  structural motifs in all fields of chemistry, the molecule demonstrates a common model system for silicon centers surrounded by sterically demanding substituents.

**Related literature**

For the synthesis of  $\text{Ph}_3\text{SiO}-t\text{-Bu}$ , see: Gilman *et al.* (1953). For the synthesis and structure of  $\text{Ph}_3\text{SiO}-i\text{-Pr}$ , see: Wojtczak *et al.* (1996). For selected transition-metal complexes containing  $\text{Ph}_3\text{SiO}$  groups, see: Bindl *et al.* (2009); Johnson *et al.* (2000); Ruiz *et al.* (2004); Schweder *et al.* (1999); Schweder *et al.* (2006); Wolff von Gudenberg *et al.* (1994). For selected main-group compounds containing  $\text{Ph}_3\text{SiO}$  units, see: Apblett & Barron (1993); Chen *et al.* (2008); Ferguson *et al.* (1996, 2005). For applications of silyl ethers in protecting group chemistry, see: Scheidt *et al.* (2002); Vintonyak & Maier (2007). For comparative  $\text{O}-\text{Si}$  distances, see: Bowes *et al.* (2002); Wojtczak *et al.* (1996) and for  $\text{C}-\text{Si}$  distances, see: Dilman *et al.* (2004); Lee *et al.* (2001); Wojtczak *et al.* (1996).

**Experimental***Crystal data*

$\text{C}_{22}\text{H}_{24}\text{OSi}$	$V = 1888.0(8)\text{ \AA}^3$
$M_r = 332.5$	$Z = 4$
Monoclinic, $P2_1/n$	Mo $K\alpha$ radiation
$a = 9.8054(12)\text{ \AA}$	$\mu = 0.13\text{ mm}^{-1}$
$b = 20.201(7)\text{ \AA}$	$T = 173\text{ K}$
$c = 10.231(2)\text{ \AA}$	$0.30 \times 0.20 \times 0.20\text{ mm}$
$\beta = 111.311(18)^\circ$	

*Data collection*

Oxford Diffraction Xcalibur S diffractometer	23180 measured reflections
Absorption correction: multi-scan ( <i>CrysAlis RED</i> ; Oxford Diffraction, 2006)	4203 independent reflections
$T_{\min} = 0.962$ , $T_{\max} = 0.975$	2597 reflections with $I > 2\sigma(I)$
	$R_{\text{int}} = 0.045$

*Refinement*

$R[F^2 > 2\sigma(F^2)] = 0.042$	220 parameters
$wR(F^2) = 0.100$	H-atom parameters constrained
$S = 0.89$	$\Delta\rho_{\max} = 0.37\text{ e \AA}^{-3}$
4203 reflections	$\Delta\rho_{\min} = -0.24\text{ e \AA}^{-3}$

Data collection: *CrysAlis CCD* (Oxford Diffraction, 2006); cell refinement: *CrysAlis RED* (Oxford Diffraction, 2006); data reduction: *CrysAlis RED*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *ORTEP-3* (Farrugia, 1997); software used to prepare material for publication: *SHELXL97*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: FB2173).

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# supporting information

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## **tert-Butoxytriphenylsilane**

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### **S1. Comment**

Siloxy groups are versatile structural subunits both in organic and inorganic chemistry, *e.g.* in the design of transition metal based catalysts (Bindl *et al.*, 2009; Schweder *et al.*, 1999) such as in the recently developed molybdenum triphenylsiloxide complex, which serves as a catalyst for alkyne metathesis (Bindl *et al.*, 2009). In the light of the impressive attainment in natural product synthesis, silyl ethers in addition proved to be an essential structural element in their role as commonly used protecting groups as they are applied for alcohol functionalities (Scheidt *et al.*, 2002; Vintonyak & Maier, 2007). Aside from several known *x*-ray structures of triphenylsiloxy substituted transition metal complexes (Bindl *et al.*, 2009; Johnson *et al.*, 2000; Ruiz *et al.*, 2004; Schweder *et al.*, 1999; Schweder *et al.*, 2006; Wolff von Gudenberg *et al.*, 1994), there have also been reported some corresponding main group compounds (Applett & Barron, 1993; Ferguson *et al.*, 1996; Ferguson *et al.*, 2005; Wojtczak *et al.*, 1996) as well as palladium allyl species that contain triphenylsilyl ether subunits (Chen *et al.*, 2008).

The title compound, *tert*-butoxytriphenylsilane, was originally synthesized by Gilman *et al.* (1953) by refluxing chlorotriphenylsilane in *tert*-butyl alcohol in the presence of dimethylaniline. While the crystal structure of Ph<sub>3</sub>SiO-*i*-Pr was found to be already determined (Wojtczak *et al.*, 1996), no structural data about the bulkier substituted Ph<sub>3</sub>SiO-*t*-Bu have been described yet.

The molecule of the title compound features a distorted tetrahedral coordination around the silicon center. Contrary to the virtually tetrahedral O—Si—C7 and O—Si—C1 bond angles of 111.34 (8)° and 112.63 (8)°, respectively, the O—Si—C13 angle with a value of 102.31 (8)° was found to be significantly smaller. The remarkable sterical hindrance between the bulky *tert*-butoxy substituent and the three phenyl groups is also reflected by the large C19—O—Si bond angle of 135.97 (12)° which is comparable to the C—O—Si angle in the structurally characterized silylenol ether isopropenyl-oxy[tris(pentafluorophenyl)]silane [138.9 (1)°] (Dilman *et al.*, 2004). However, the value of this angle in both the latter and the title compound is noticeably larger than the respective angle in *iso*-propoxytriphenylsilane [124.8 (1)°] (Wojtczak *et al.*, 1996). In the title structure, the three C—Si bond lengths have values of 1.8545 (19) Å (C7—Si), 1.8541 (18) Å (C13—Si) and 1.8623 (19) Å (C1—Si) and thus are comparable to the distances found in the related systems (Dilman *et al.*, 2004; Lee *et al.*, 2001; Wojtczak *et al.*, 1996). It is also worth mentioning that the interatomic O—Si distance with 1.6244 (13) Å is slightly shorter than those in the reported tetrameric triphenylsilanol [values denoted from 1.6397 (19) Å to 1.646 (2) Å] (Bowes *et al.*, 2002) and the aforementioned Ph<sub>3</sub>SiO-*i*-Pr [1.641 (2) Å] (Wojtczak *et al.*, 1996). The distance between the aryl H4 atoms (H4—H4'; -x+1, -y, -z+2) equals to 2.2924 (7) Å and it was identified as the shortest intermolecular distance in the structure.

### **S2. Experimental**

Potassium-*tert*-butoxide (503 mg, 4.48 mmol), dissolved in absolute tetrahydrofuran (4 ml), was added dropwise at 0°C to a stirred solution of chlorotriphenylsilane (1.10 g, 3.73 mmol) in 7 ml of absolute tetrahydrofuran. The resulting

reaction mixture was stirred for 4 h at room temperature. After saturated aqueous NH<sub>4</sub>Cl solution (10 ml) had been added, the organic layer was separated and the aqueous phase extracted with diethyl ether (2×10 ml and 2×5 ml). The combined ether extracts were washed with water (10 ml) and then dried over anhydrous Na<sub>2</sub>SO<sub>4</sub>. After filtration, all volatiles were removed under reduced pressure to yield 90% (1.11 g) of a white solid. The crude product was purified by Kugelrohr distillation (140°C, 0.8 mbar). Recrystallization of the title compound from diethyl ether resulted in the formation of small and transparent plates in the range of 0.30 × 0.20 × 0.20 mm, suitable for single-crystal x-ray studies.

<sup>1</sup>H-NMR (300.1 MHz, CDCl<sub>3</sub>):  $\delta$  = 1.29 [s, 9H; C(CH<sub>3</sub>)<sub>3</sub>], 7.34–7.45 (m, 9H; H<sub>aromat.</sub>), 7.68–7.71 (m, 6H; H<sub>aromat.</sub>).

{<sup>1</sup>H}{<sup>13</sup>C}-NMR (75.5 MHz, CDCl<sub>3</sub>):  $\delta$  = 32.1 (3 C) [C(CH<sub>3</sub>)<sub>3</sub>], 74.1 (1 C) [C(CH<sub>3</sub>)<sub>3</sub>], 127.6 (6 C) (C<sub>meta</sub>), 129.5 (3 C) (C<sub>para</sub>), 135.5 (6 C) (C<sub>ortho</sub>), 136.6 (3 C) (C<sub>ipso</sub>).

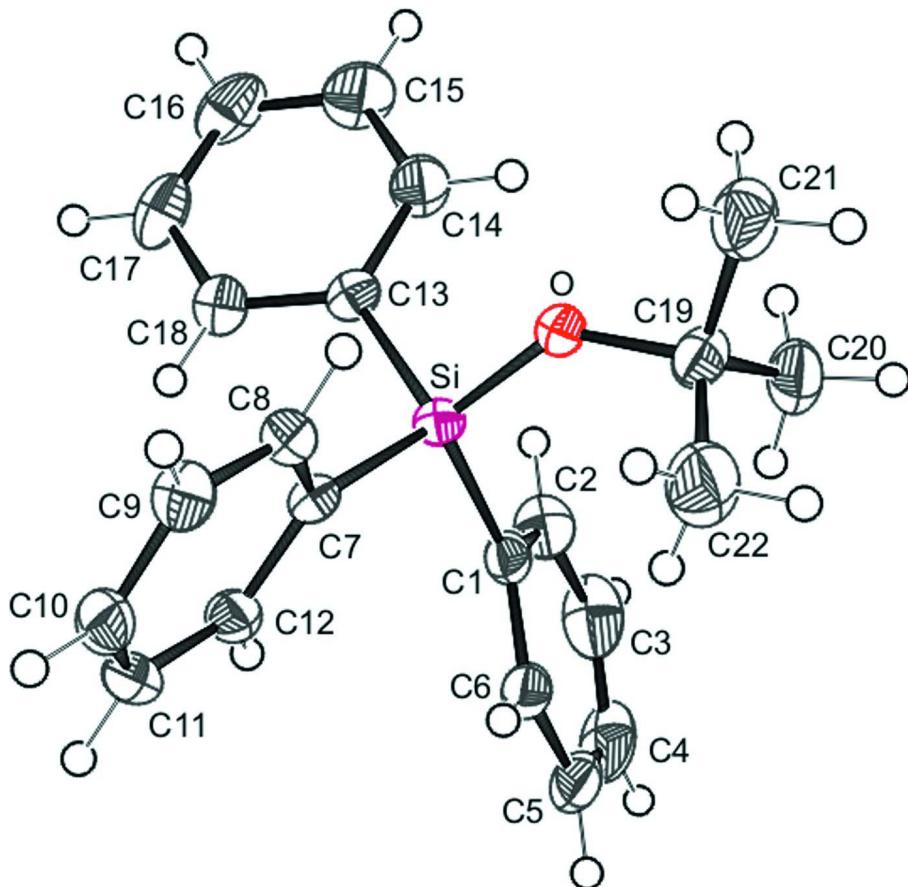
{<sup>1</sup>H}{<sup>29</sup>Si}-NMR (59.6 MHz, CDCl<sub>3</sub>):  $\delta$  = -22.2 (1Si).

GC/EI—MS (70 eV):  $t_R$  = 7.06 min; m/z (%) = 332 (11) [M<sup>+</sup>], 317 (62) [(M-Me)<sup>+</sup>], 259 (100) [(Ph<sub>3</sub>Si)<sup>+</sup>], 199 (79) [(Ph<sub>2</sub>SiHO)<sup>+</sup>], 105 (5) [(SiPh)<sup>+</sup>].

**Analysis:** C<sub>22</sub>H<sub>24</sub>OSi calculated: C 79.47%, H 7.28%; found: C 79.4%, H 7.3%.

### S3. Refinement

All the H atoms could have been discerned in the difference electron density map. However, the H atoms were refined in their idealized geometric positions using the riding model approximation with  $U_{\text{iso}}(\text{H}) = 1.5U_{\text{eq}}(\text{C})$  for the methyl H atoms and of  $U_{\text{iso}}(\text{H}) = 1.2U_{\text{eq}}(\text{C})$  for the aryl H atoms. The applied C—H distance constraints: methyl 0.98 Å; aryl 0.95 Å.



**Figure 1**

The title molecule *tert*-butoxytriphenylsilane with the displacement ellipsoids drawn at the 50% probability level.

***tert*-Butoxytriphenylsilane***Crystal data*

C<sub>22</sub>H<sub>24</sub>OSi  
 $M_r = 332.5$   
 Monoclinic, P2<sub>1</sub>/n  
 Hall symbol: -P 2yn  
 $a = 9.8054 (12)$  Å  
 $b = 20.201 (7)$  Å  
 $c = 10.231 (2)$  Å  
 $\beta = 111.311 (18)^\circ$   
 $V = 1888.0 (8)$  Å<sup>3</sup>  
 $Z = 4$

$F(000) = 712$   
 $D_x = 1.170 \text{ Mg m}^{-3}$   
 Mo K $\alpha$  radiation,  $\lambda = 0.71073$  Å  
 Cell parameters from 6858 reflections  
 $\theta = 2.2\text{--}29.1^\circ$   
 $\mu = 0.13 \text{ mm}^{-1}$   
 $T = 173$  K  
 Block, colourless  
 $0.30 \times 0.20 \times 0.20$  mm

*Data collection*

Oxford Diffraction Xcalibur S  
 diffractometer  
 Radiation source: Enhance (Mo) X-ray Source  
 Graphite monochromator  
 $\omega$  scans  
 Absorption correction: multi-scan  
*(CrysAlis RED; Oxford Diffraction, 2006)*  
 $T_{\min} = 0.962$ ,  $T_{\max} = 0.975$

23180 measured reflections  
 4203 independent reflections  
 2597 reflections with  $I > 2\sigma(I)$   
 $R_{\text{int}} = 0.045$   
 $\theta_{\max} = 27.2^\circ$ ,  $\theta_{\min} = 2.4^\circ$   
 $h = -12 \rightarrow 12$   
 $k = -26 \rightarrow 25$   
 $l = -13 \rightarrow 13$

*Refinement*

Refinement on  $F^2$   
 Least-squares matrix: full  
 $R[F^2 > 2\sigma(F^2)] = 0.042$   
 $wR(F^2) = 0.100$   
 $S = 0.89$   
 4203 reflections  
 220 parameters  
 0 restraints  
 Primary atom site location: structure-invariant  
 direct methods

Secondary atom site location: difference Fourier  
 map  
 Hydrogen site location: difference Fourier map  
 H-atom parameters constrained  
 $w = 1/[\sigma^2(F_o^2) + (0.0535P)^2]$   
 where  $P = (F_o^2 + 2F_c^2)/3$   
 $(\Delta/\sigma)_{\max} < 0.001$   
 $\Delta\rho_{\max} = 0.37 \text{ e } \text{\AA}^{-3}$   
 $\Delta\rho_{\min} = -0.24 \text{ e } \text{\AA}^{-3}$

*Special details*

**Experimental.** empirical absorption correction using spherical harmonics, implemented in SCALE3 ABSPACK scaling algorithm

**Geometry.** All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

**Refinement.** Refinement of  $F^2$  against ALL reflections. The weighted  $R$ -factor  $wR$  and goodness of fit  $S$  are based on  $F^2$ , conventional  $R$ -factors  $R$  are based on  $F$ , with  $F$  set to zero for negative  $F^2$ . The threshold expression of  $F^2 > \sigma(F^2)$  is used only for calculating  $R$ -factors(gt) etc. and is not relevant to the choice of reflections for refinement.  $R$ -factors based on  $F^2$  are statistically about twice as large as those based on  $F$ , and  $R$ -factors based on ALL data will be even larger.

*Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters ( $\text{\AA}^2$ )*

	<i>x</i>	<i>y</i>	<i>z</i>	$U_{\text{iso}}^*/U_{\text{eq}}$
C1	0.27284 (19)	0.12279 (9)	0.61661 (17)	0.0278 (4)
C2	0.1958 (2)	0.08722 (10)	0.68339 (19)	0.0403 (5)
H2	0.0935	0.0808	0.637	0.048*
C3	0.2644 (3)	0.06106 (11)	0.8152 (2)	0.0556 (6)
H3	0.2098	0.0363	0.8583	0.067*
C4	0.4122 (3)	0.07079 (12)	0.8846 (2)	0.0615 (7)
H4	0.4593	0.0535	0.9764	0.074*
C5	0.4911 (3)	0.10533 (11)	0.8215 (2)	0.0506 (6)
H5	0.5932	0.1119	0.8692	0.061*
C6	0.4227 (2)	0.13062 (9)	0.68881 (19)	0.0358 (5)
H6	0.4789	0.154	0.6454	0.043*
C7	0.27111 (17)	0.23135 (8)	0.41104 (17)	0.0238 (4)
C8	0.27112 (18)	0.24872 (9)	0.27948 (18)	0.0285 (4)
H8	0.223	0.2207	0.2017	0.034*
C9	0.3389 (2)	0.30526 (9)	0.25882 (19)	0.0331 (4)
H9	0.3368	0.3162	0.1678	0.04*
C10	0.40953 (19)	0.34582 (9)	0.3708 (2)	0.0349 (4)
H10	0.4588	0.3843	0.3576	0.042*
C11	0.40926 (19)	0.33105 (9)	0.50166 (19)	0.0337 (5)
H11	0.4562	0.3598	0.5784	0.04*
C12	0.34073 (19)	0.27453 (9)	0.52133 (18)	0.0292 (4)
H12	0.3409	0.2647	0.6122	0.035*
C13	-0.01766 (18)	0.17492 (9)	0.40683 (17)	0.0262 (4)
C14	-0.1271 (2)	0.12846 (10)	0.3473 (2)	0.0400 (5)
H14	-0.101	0.0856	0.3261	0.048*
C15	-0.2717 (2)	0.14281 (12)	0.3185 (2)	0.0533 (6)
H15	-0.3444	0.1101	0.2776	0.064*
C16	-0.3119 (2)	0.20462 (12)	0.3486 (2)	0.0504 (6)
H16	-0.4121	0.2147	0.3288	0.061*
C17	-0.2070 (2)	0.25123 (10)	0.4069 (2)	0.0425 (5)
H17	-0.2342	0.294	0.4272	0.051*
C18	-0.0612 (2)	0.23652 (9)	0.43663 (18)	0.0315 (4)
H18	0.0108	0.2694	0.4784	0.038*
C19	0.2491 (2)	0.04775 (9)	0.29651 (19)	0.0333 (4)
C20	0.2387 (2)	-0.01047 (10)	0.3858 (2)	0.0500 (6)
H20A	0.2889	0.0004	0.4852	0.075*
H20B	0.285	-0.0493	0.3621	0.075*
H20C	0.1356	-0.0201	0.3679	0.075*
C21	0.1796 (3)	0.02943 (11)	0.1418 (2)	0.0527 (6)
H21A	0.0764	0.018	0.1196	0.079*
H21B	0.2311	-0.0086	0.1223	0.079*
H21C	0.1864	0.0671	0.0842	0.079*
C22	0.4025 (2)	0.06981 (12)	0.3291 (3)	0.0613 (7)
H22A	0.404	0.1062	0.2664	0.092*
H22B	0.4607	0.0328	0.3159	0.092*

H22C	0.4439	0.085	0.4267	0.092*
O	0.16116 (12)	0.10112 (6)	0.31536 (11)	0.0266 (3)
Si	0.17626 (5)	0.15575 (2)	0.43643 (5)	0.02347 (13)

*Atomic displacement parameters ( $\text{\AA}^2$ )*

	$U^{11}$	$U^{22}$	$U^{33}$	$U^{12}$	$U^{13}$	$U^{23}$
C1	0.0329 (10)	0.0245 (10)	0.0250 (9)	0.0035 (8)	0.0092 (8)	-0.0018 (8)
C2	0.0516 (13)	0.0398 (12)	0.0318 (11)	0.0006 (10)	0.0180 (10)	0.0021 (9)
C3	0.094 (2)	0.0419 (14)	0.0394 (13)	0.0094 (13)	0.0348 (14)	0.0088 (11)
C4	0.098 (2)	0.0445 (15)	0.0280 (12)	0.0286 (14)	0.0059 (13)	0.0077 (11)
C5	0.0549 (14)	0.0406 (13)	0.0373 (12)	0.0218 (11)	-0.0060 (11)	-0.0078 (10)
C6	0.0378 (11)	0.0305 (11)	0.0320 (11)	0.0081 (9)	0.0042 (9)	-0.0047 (9)
C7	0.0190 (8)	0.0253 (9)	0.0261 (10)	0.0020 (7)	0.0069 (7)	0.0019 (8)
C8	0.0297 (10)	0.0275 (10)	0.0268 (10)	0.0004 (8)	0.0088 (8)	-0.0013 (8)
C9	0.0383 (11)	0.0327 (11)	0.0314 (11)	0.0013 (9)	0.0162 (9)	0.0046 (9)
C10	0.0326 (10)	0.0257 (10)	0.0460 (12)	-0.0034 (9)	0.0140 (9)	0.0053 (9)
C11	0.0322 (10)	0.0297 (11)	0.0319 (11)	-0.0064 (8)	0.0029 (8)	-0.0030 (8)
C12	0.0299 (10)	0.0293 (10)	0.0250 (9)	-0.0008 (8)	0.0060 (8)	0.0012 (8)
C13	0.0251 (9)	0.0294 (10)	0.0256 (9)	0.0010 (8)	0.0108 (7)	0.0060 (8)
C14	0.0265 (10)	0.0374 (12)	0.0571 (13)	-0.0021 (9)	0.0164 (9)	-0.0025 (10)
C15	0.0244 (10)	0.0573 (16)	0.0770 (16)	-0.0071 (11)	0.0170 (11)	0.0003 (13)
C16	0.0267 (11)	0.0609 (16)	0.0673 (15)	0.0102 (11)	0.0214 (11)	0.0186 (13)
C17	0.0437 (12)	0.0417 (13)	0.0516 (13)	0.0170 (11)	0.0285 (10)	0.0152 (10)
C18	0.0341 (10)	0.0313 (11)	0.0331 (11)	0.0008 (9)	0.0169 (8)	0.0034 (9)
C19	0.0318 (10)	0.0343 (11)	0.0334 (11)	0.0086 (9)	0.0113 (8)	0.0021 (9)
C20	0.0624 (15)	0.0318 (12)	0.0506 (13)	0.0106 (11)	0.0142 (11)	0.0014 (10)
C21	0.0675 (16)	0.0492 (14)	0.0397 (13)	0.0188 (12)	0.0176 (11)	-0.0022 (11)
C22	0.0397 (13)	0.0515 (15)	0.0967 (19)	0.0006 (12)	0.0295 (13)	-0.0100 (13)
O	0.0239 (6)	0.0260 (7)	0.0280 (7)	0.0030 (5)	0.0070 (5)	-0.0026 (5)
Si	0.0205 (2)	0.0252 (3)	0.0237 (3)	-0.0009 (2)	0.00684 (18)	-0.0001 (2)

*Geometric parameters ( $\text{\AA}$ ,  $^\circ$ )*

C1—C2	1.389 (2)	C13—C14	1.388 (3)
C1—C6	1.393 (2)	C13—Si	1.8544 (17)
C1—Si	1.8626 (18)	C14—C15	1.371 (3)
C2—C3	1.375 (3)	C14—H14	0.95
C2—H2	0.95	C15—C16	1.378 (3)
C3—C4	1.376 (3)	C15—H15	0.95
C3—H3	0.95	C16—C17	1.362 (3)
C4—C5	1.366 (3)	C16—H16	0.95
C4—H4	0.95	C17—C18	1.382 (2)
C5—C6	1.375 (3)	C17—H17	0.95
C5—H5	0.95	C18—H18	0.95
C6—H6	0.95	C19—O	1.437 (2)
C7—C8	1.391 (2)	C19—C22	1.485 (3)
C7—C12	1.393 (2)	C19—C20	1.516 (3)

C7—Si	1.8549 (18)	C19—C21	1.524 (3)
C8—C9	1.376 (2)	C20—H20A	0.98
C8—H8	0.95	C20—H20B	0.98
C9—C10	1.374 (2)	C20—H20C	0.98
C9—H9	0.95	C21—H21A	0.98
C10—C11	1.373 (3)	C21—H21B	0.98
C10—H10	0.95	C21—H21C	0.98
C11—C12	1.376 (2)	C22—H22A	0.98
C11—H11	0.95	C22—H22B	0.98
C12—H12	0.95	C22—H22C	0.98
C13—C18	1.385 (2)	O—Si	1.6251 (12)
C2—C1—C6	117.08 (17)	C14—C15—H15	120
C2—C1—Si	120.00 (14)	C16—C15—H15	120
C6—C1—Si	122.90 (14)	C17—C16—C15	119.53 (19)
C3—C2—C1	121.4 (2)	C17—C16—H16	120.2
C3—C2—H2	119.3	C15—C16—H16	120.2
C1—C2—H2	119.3	C16—C17—C18	120.27 (19)
C2—C3—C4	119.9 (2)	C16—C17—H17	119.9
C2—C3—H3	120	C18—C17—H17	119.9
C4—C3—H3	120	C17—C18—C13	121.47 (18)
C5—C4—C3	120.0 (2)	C17—C18—H18	119.3
C5—C4—H4	120	C13—C18—H18	119.3
C3—C4—H4	120	O—C19—C22	110.67 (16)
C4—C5—C6	120.0 (2)	O—C19—C20	109.03 (15)
C4—C5—H5	120	C22—C19—C20	112.45 (17)
C6—C5—H5	120	O—C19—C21	104.93 (14)
C5—C6—C1	121.6 (2)	C22—C19—C21	109.93 (17)
C5—C6—H6	119.2	C20—C19—C21	109.56 (17)
C1—C6—H6	119.2	C19—C20—H20A	109.5
C8—C7—C12	116.97 (16)	C19—C20—H20B	109.5
C8—C7—Si	121.30 (13)	H20A—C20—H20B	109.5
C12—C7—Si	121.69 (13)	C19—C20—H20C	109.5
C9—C8—C7	121.87 (17)	H20A—C20—H20C	109.5
C9—C8—H8	119.1	H20B—C20—H20C	109.5
C7—C8—H8	119.1	C19—C21—H21A	109.5
C10—C9—C8	119.50 (17)	C19—C21—H21B	109.5
C10—C9—H9	120.3	H21A—C21—H21B	109.5
C8—C9—H9	120.3	C19—C21—H21C	109.5
C11—C10—C9	120.31 (17)	H21A—C21—H21C	109.5
C11—C10—H10	119.8	H21B—C21—H21C	109.5
C9—C10—H10	119.8	C19—C22—H22A	109.5
C10—C11—C12	119.81 (17)	C19—C22—H22B	109.5
C10—C11—H11	120.1	H22A—C22—H22B	109.5
C12—C11—H11	120.1	C19—C22—H22C	109.5
C11—C12—C7	121.52 (17)	H22A—C22—H22C	109.5
C11—C12—H12	119.2	H22B—C22—H22C	109.5
C7—C12—H12	119.2	C19—O—Si	135.97 (11)

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C18—C13—C14	116.93 (16)	O—Si—C13	102.32 (7)
C18—C13—Si	122.11 (13)	O—Si—C7	111.33 (7)
C14—C13—Si	120.89 (14)	C13—Si—C7	109.98 (8)
C15—C14—C13	121.72 (19)	O—Si—C1	112.61 (7)
C15—C14—H14	119.1	C13—Si—C1	111.02 (8)
C13—C14—H14	119.1	C7—Si—C1	109.42 (8)
C14—C15—C16	120.1 (2)		

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